## TD3F30MB

# Surface Mount Fast Recovery Bridge Rectifier Reverse Voltage - 1000 V Forward Current - 3 A

#### **Features**

- Glass passivated chip junction
- Fast reverse recovery time
- Designed for Surface Mount Application

# 4 Output Cathode ( - )

**UMSB** Package

Output Anode (+)

DESCRIPTION
Input Pin ( ~ )
Input Pin ( ~ )

PINNING

#### **Mechanical Data**

· Case: Molded plastic, UMSB

•Terminals: solderable per MIL-STD-750, Method 2026

#### **Absolute Maximum Ratings and Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Б	Symbols	Value	Units		
Parameter	Marking	FMB30M	-		
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	1000	V		
Maximum RMS Voltage	V <sub>RMS</sub>	700	V		
Maximum DC Blocking Voltage	V <sub>DC</sub>	1000	V		
Average Rectified Output Current	I <sub>F(AV)</sub>	3	А		
Peak Forward Surge Current 8.3 ms Single Half-sine-wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	100	А		
Peak Forward Surge Current 1 ms Single Half-square-wave Superimposed on Rated Load	I <sub>FSM</sub>	180	А		
I <sup>2</sup> t Rating for fusing (t = 8.3 mS)	l <sup>2</sup> t	41.5	A <sup>2</sup> S		
I <sup>2</sup> t Rating for fusing (t = 1 mS)	l <sup>2</sup> t	16.2	A <sup>2</sup> S		
Maximum Forward Voltage at 3 A	V <sub>F</sub>	1	V		
Maximum DC Reverse Current at Rated DC at $T_a = 25^{\circ}$ C  Blocking Voltage DC Blocking Voltage at $T_a = 125^{\circ}$ C	I <sub>R</sub>	5 200	μΑ		
Typical Junction Capacitance 1)	CJ	40	pF		
Typical Thermal Resistance <sup>2)</sup>	$R_{\theta JA}$	35	°C/W		
Maximum Reverse Recovery Time <sup>3)</sup>	t <sub>rr</sub>	500	ns		
Operating Junction and Storage Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	- 55 to + 150	°C		

<sup>1)</sup> Measured at 1MHz and applied reverse voltage of 4 V D.C.



<sup>&</sup>lt;sup>2)</sup> Mounted on glass epoxy PC board with 4 x 1.5cm x1.5cm copper pad.

 $<sup>^{3)}</sup>$  Measured with IF = 0.5 A, IR = 1 A, Irr = 0.25 A .

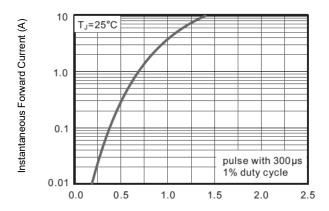
Instantaneous Reverse Current (µA)

0.1

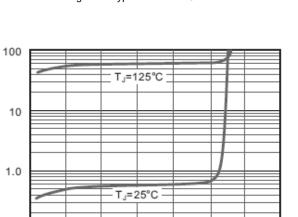
00

20

40



Instantaneous Forward Voltage (V)
Figure 1. Typical Forward Characteristics



Percent of Rated Peak Reverse Voltage (%) Figure 3. Typical Reverse Characteristics

80

100

120

140

60

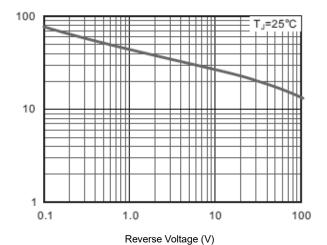
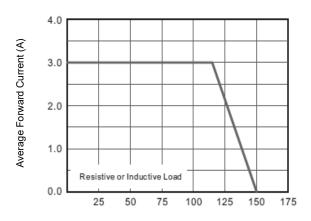
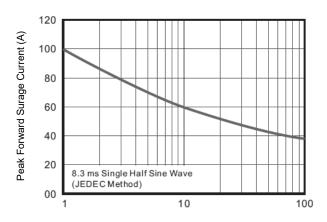


Figure 5. Typical Junction Capacitance



Ambient Temperature (°C)
Figure 2. Forward Current Derating Curve

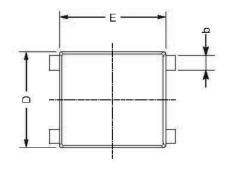


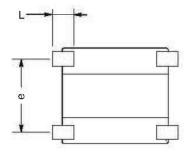
Number of Cycles at 60Hz
Figure 4. Maximum Non-Repetitive Peak Forward
Surage Current

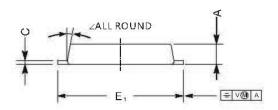


PACKAGE OUTLINE UMSB

# Plastic surface mounted package; 4 leads







UNIT	Α	С	D	Е	E <sub>1</sub>	L	е	b	_
mm	1.5	0.29	7	7.6	8.9	1.6	5.3	1.15	10°
	1.3	0.17	6.2	7.1	7.9	1	4.9	0.95	

## **Recommended Soldering Footprint**

